

# 7MBP200VEA120-50

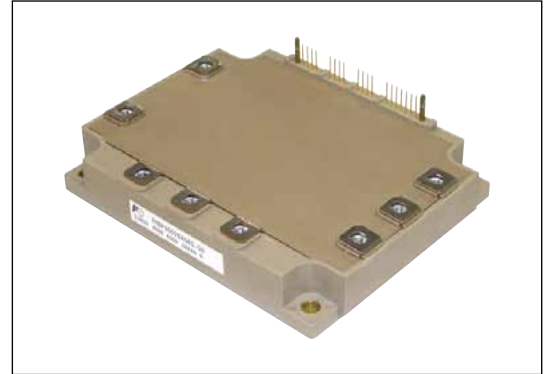
**IGBT Modules**

## IGBT MODULE (V series)

### 1200V / 200A / IPM

#### ■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



#### ■ Maximum Ratings and Characteristics

##### ● Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ , $V_{cc}=15\text{V}$ unless otherwise specified)

Items	Symbol	Min.	Max.	Units		
Collector-Emitter Voltage (*1)	$V_{CES}$	0	1200	V		
Short Circuit Voltage	$V_{SC}$	400	800	V		
Inverter	Collector Current	DC	$I_C$	-	200	A
		1ms	$I_{cp}$	-	400	A
		Duty=100% (*2)	$-I_C$	-	200	A
Collector Power Dissipation	1 device (*3)	$P_C$	-	961	W	
Brake	Collector Current	DC	$I_C$	-	100	A
		1ms	$I_{cp}$	-	200	A
	Forward Current of Diode		$I_F$	-	100	A
	Collector Power Dissipation	1 device (*3)	$P_C$	-	581	W
Supply Voltage of Pre-Driver (*4)	$V_{CC}$	-0.5	20	V		
Input Signal Voltage (*5)	$V_{in}$	-0.5	$V_{CC}+0.5$	V		
Alarm Signal Voltage (*6)	$V_{ALM}$	-0.5	$V_{CC}$	V		
Alarm Signal Current (*7)	$I_{ALM}$	-	20	mA		
Junction Temperature	$T_J$	-	150	$^\circ\text{C}$		
Operating Case Temperature	$T_{opr}$	-20	110	$^\circ\text{C}$		
Storage Temperature	$T_{stg}$	-40	125	$^\circ\text{C}$		
Solder Temperature (*8)	$T_{sol}$	-	260	$^\circ\text{C}$		
Isolating Voltage (*9)	$V_{iso}$	-	AC2500	Vrms		
Screw Torque	Terminal (M5)	-	-	-		
	Mounting (M5)	-	-	3.5	Nm	

Note \*1:  $V_{CES}$  shall be applied to the input voltage between all Collector and Emitter. [ P1- (U, V, W, B), P2- (U, V, W, B), (U, V, W, B)-N1, (U, V, W, B)-N2 ]

Note \*2: Duty=125 $^\circ\text{C}/R_{th(j-c)}$  / ( $I_F \times V_F$  Max.)  $\times 100$

Note \*3:  $P_C=125^\circ\text{C}/R_{th(j-c)}$  (Inverter & Brake)

Note \*4:  $V_{CC}$  shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 14 and 13.

Note \*5:  $V_{in}$  shall be applied to the input voltage between terminal No.2 and 1, 6 and 5, 10 and 9, 15~18 and 13.

Note \*6:  $V_{ALM}$  shall be applied to the voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 19 and 13.

Note \*7:  $I_{ALM}$  shall be applied to the input current to terminal No.4, 8, 12 and 19.

Note \*8: Immersion time 10 $\pm$ 1 sec. 1 time.

Note \*9: Terminal to base, 50/60Hz sine wave 1 min. All terminals should be connected together during the test.

● Electrical Characteristics ( $T_J=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$  unless otherwise specified)

Items	Symbol	Conditions	Min.	Typ.	Max.	Units		
Inverter	Collector Current at off signal input	$I_{CES}$	$V_{CE}=1200\text{V}$		-	-	1.0	mA
	Collector-Emitter saturation voltage (*10)	$V_{CE(sat)}$	$I_C=200\text{A}$	Terminal	-	-	2.30	V
				Chip	-	1.70	-	V
	Forward voltage of FWD (*10)	$V_F$	$I_F=200\text{A}$	Terminal	-	-	2.75	V
Chip				-	2.10	-	V	
Brake	Collector Current at off signal input	$I_{CES}$	$V_{CE}=1200\text{V}$		-	-	1.0	mA
	Collector-Emitter saturation voltage (*10)	$V_{CE(sat)}$	$I_C=100\text{A}$	Terminal	-	-	2.20	V
				Chip	-	1.70	-	V
	Forward voltage of FWD (*10)	$V_F$	$I_F=100\text{A}$	Terminal	-	-	2.85	V
Chip				-	2.35	-	V	
Switching time	$t_{on}$	$V_{DC}=600\text{V}$ , $T_J=125^\circ\text{C}$ , $I_C=200\text{A}$	1.1	-	-	$\mu\text{s}$		
	$t_{off}$		-	-	2.1	$\mu\text{s}$		
	$t_{rr}$	$V_{DC}=600\text{V}$ , $I_F=200\text{A}$	-	-	0.3	$\mu\text{s}$		
Supply current of P-side pre-driver (per one unit)	$I_{ccp}$	Switching Frequency= 0-15kHz $T_C=-20\sim 110^\circ\text{C}$	-	-	42	mA		
Supply current of N-side pre-driver	$I_{ccn}$		-	-	142	mA		
Input signal threshold voltage	$V_{in(th)(on)}$	$V_{in}-\text{GND}$	ON	1.2	1.4	1.6	V	
	$V_{in(th)(off)}$		OFF	1.5	1.7	1.9	V	
Over Current Protection Level	Inverter	$I_{OC}$	$T_J=125^\circ\text{C}$	300	-	-	A	
				Brake	150	-	-	A
Over Current Protection Delay time	$t_{dOC}$	$T_J=125^\circ\text{C}$	-	5	-	$\mu\text{s}$		
Short Circuit Protection Delay time	$t_{sc}$	$T_J=125^\circ\text{C}$	-	2	3	$\mu\text{s}$		
IGBT Chips Over Heating Protection Temperature Level	$T_{J(OH)}$	Surface of IGBT Chips	150	-	-	$^\circ\text{C}$		
Over Heating Protection Hysteresis	$T_{JH}$		-	20	-	$^\circ\text{C}$		
Under Voltage Protection Level	$V_{UV}$		11.0	-	12.5	V		
Under Voltage Protection Hysteresis	$V_H$		0.2	0.5	-	V		
Alarm Signal Hold Time	$t_{ALM(OC)}$	ALM-GND $T_C=-20\sim 110^\circ\text{C}$	$V_{CC}\geq 10\text{V}$	1.0	2.0	2.4	ms	
	$t_{ALM(UV)}$			2.5	4.0	4.9	ms	
	$t_{ALM(T_{J(OH)})}$			5.0	8.0	11.0	ms	
Resistance for current limit	$R_{ALM}$		960	1265	1570	$\Omega$		

Note \*10: The Max value is a case where it measures from P2- (U, V, W, B), (U, V, W, B)-N2.

● Thermal Characteristics ( $T_c = 25^\circ\text{C}$ )

Items	Symbol	Min.	Typ.	Max.	Units		
Junction to Case Thermal Resistance (*11)	Inverter	IGBT	$R_{th(j-c)Q}$	-	-	0.130	$^\circ\text{C}/\text{W}$
		FWD	$R_{th(j-c)D}$	-	-	0.195	$^\circ\text{C}/\text{W}$
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	0.215	$^\circ\text{C}/\text{W}$
		FWD	$R_{th(j-c)D}$	-	-	0.400	$^\circ\text{C}/\text{W}$
Case to Fin Thermal Resistance with Compound	$R_{th(c-f)}$	-	0.05	-	$^\circ\text{C}/\text{W}$		

Note \*11: For 1device, the measurement point of the case is just under the chip.

● Noise Immunity ( $V_{DC}=600\text{V}$ ,  $V_{CC}=15\text{V}$ )

Items	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width $1\mu\text{s}$ , polarity $\pm$ , 10 min. Judge : no over-current, no miss operating	$\pm 2.0$	-	-	kV

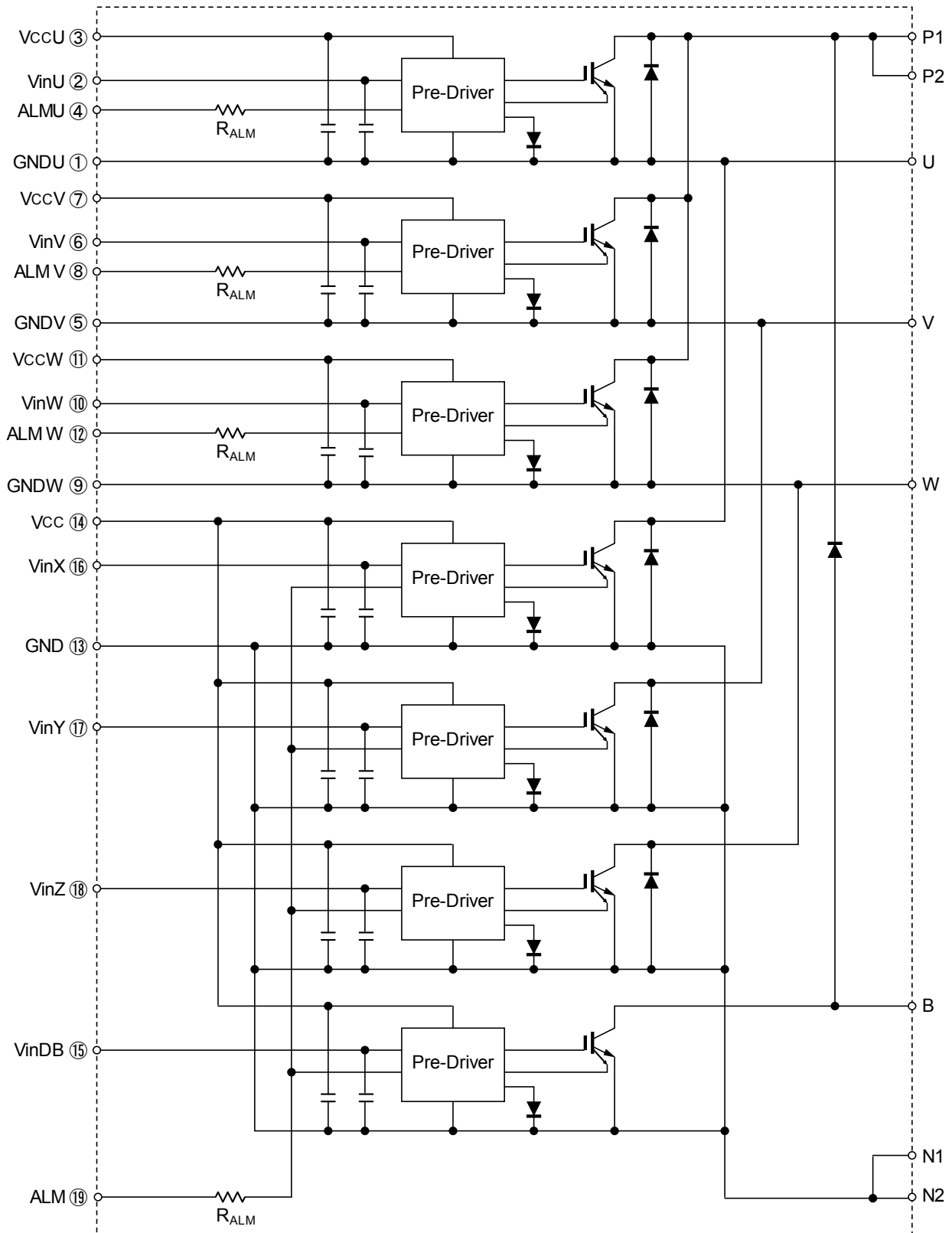
● Recommended Operating Conditions

Items	Symbol	Min.	Typ.	Max.	Units
DC Bus Voltage	$V_{DC}$	-	-	800	V
Power Supply Voltage of Pre-Driver	$V_{CC}$	13.5	15.0	16.5	V
Switching frequency of IPM	$f_{sw}$	-	-	20	kHz
Arm shoot through blocking time for IPM's input signal	$t_{dead}$	1.0	-	-	$\mu\text{s}$
Screw Torque (M5)	-	2.5	-	3.5	Nm

● Weight

Items	Symbol	Min.	Typ.	Max.	Units
Weight	Wt	-	940	-	g

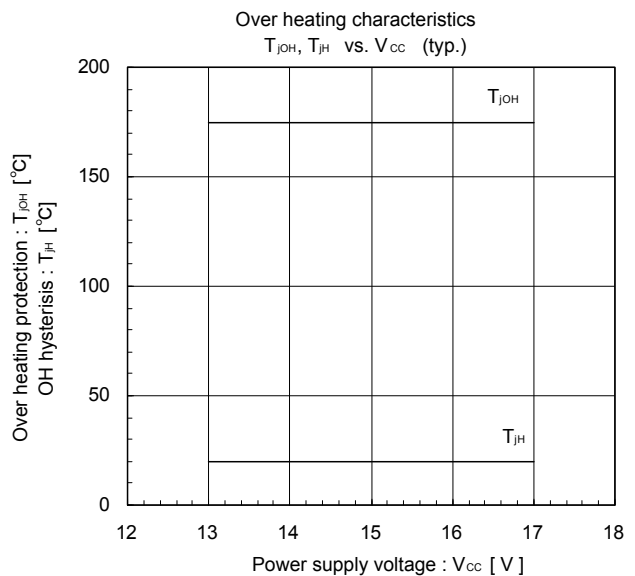
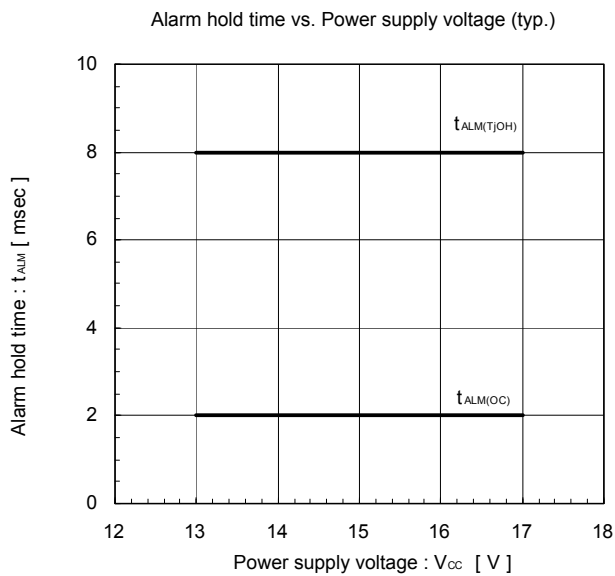
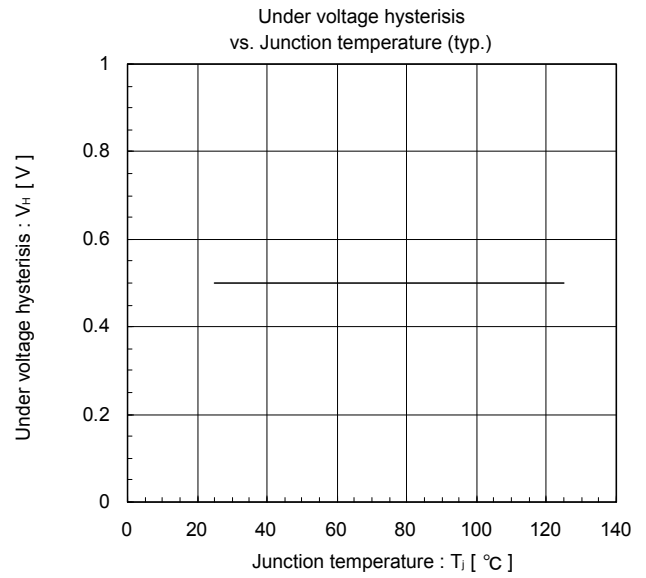
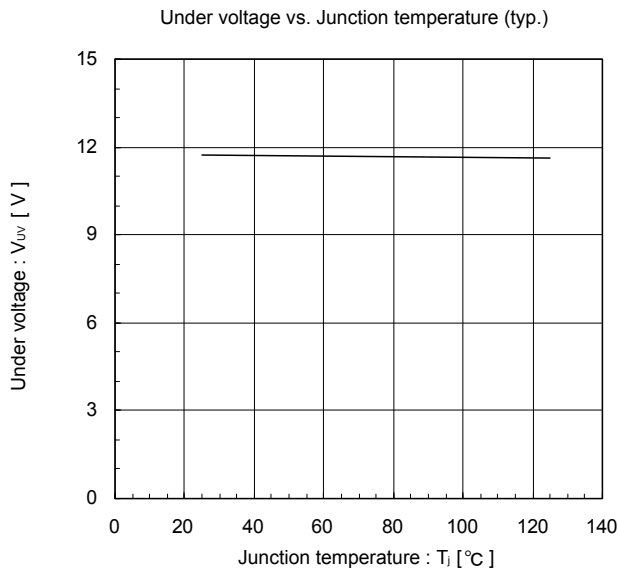
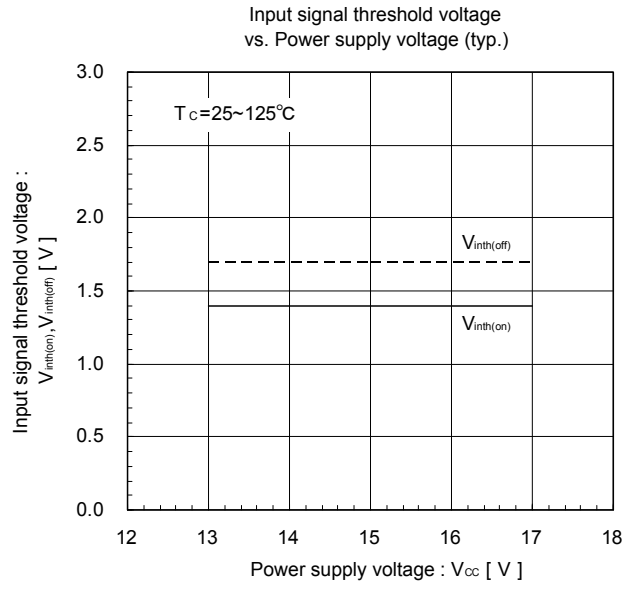
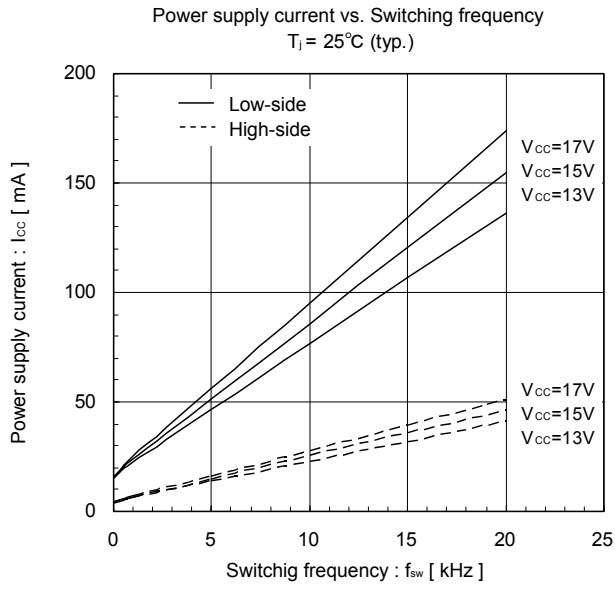
■ Block Diagram



Pre-drivers include following functions

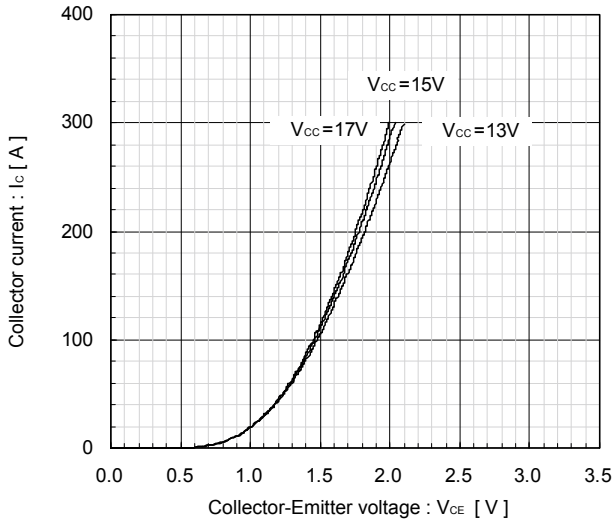
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

■ Characteristics (Representative)

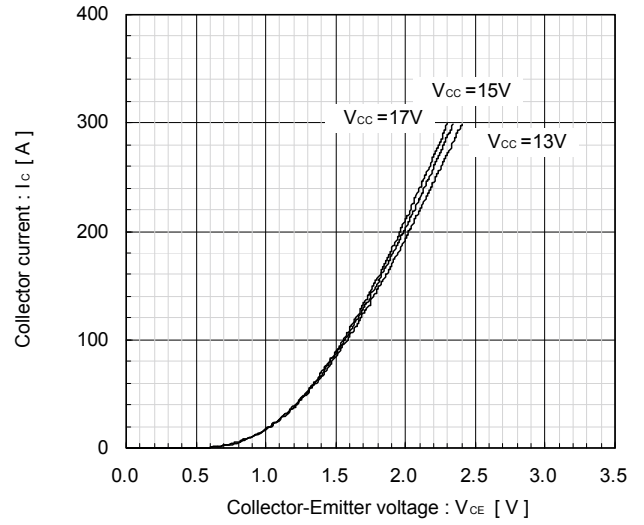


Inverter

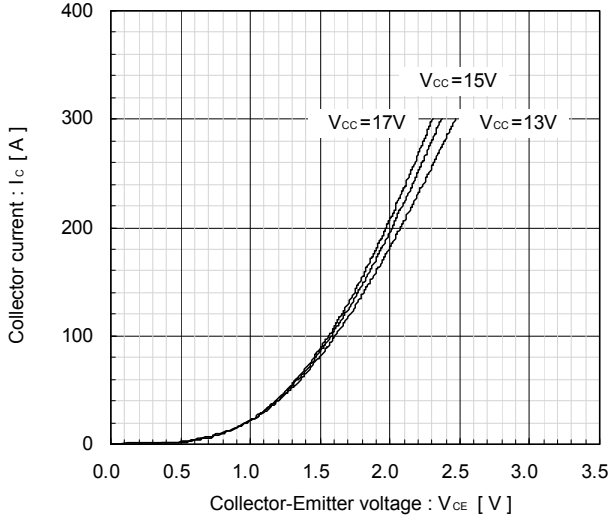
Collector current vs. Collector-Emitter voltage  
 $T_j = 25^\circ\text{C}$  [Chip] (typ.)



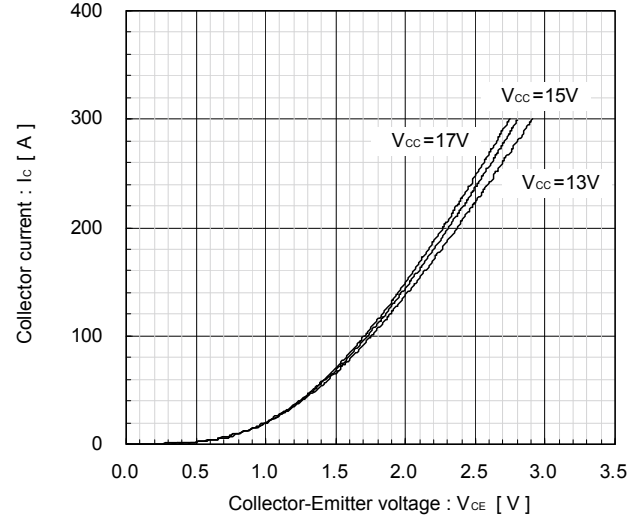
Collector current vs. Collector-Emitter voltage  
 $T_j = 25^\circ\text{C}$  [Terminal] (typ.)



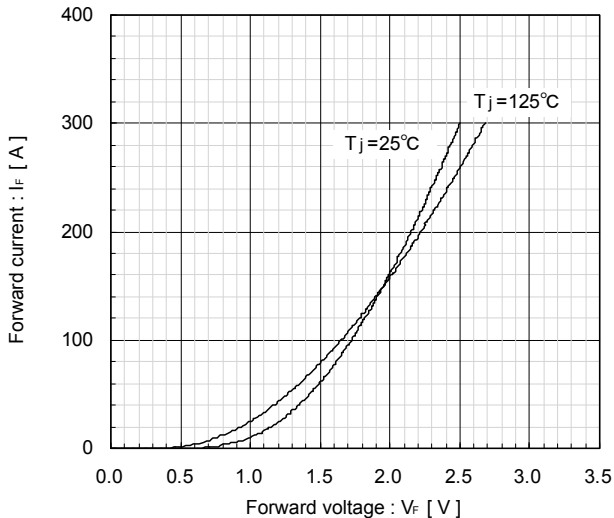
Collector current vs. Collector-Emitter voltage  
 $T_j = 125^\circ\text{C}$  [Chip] (typ.)



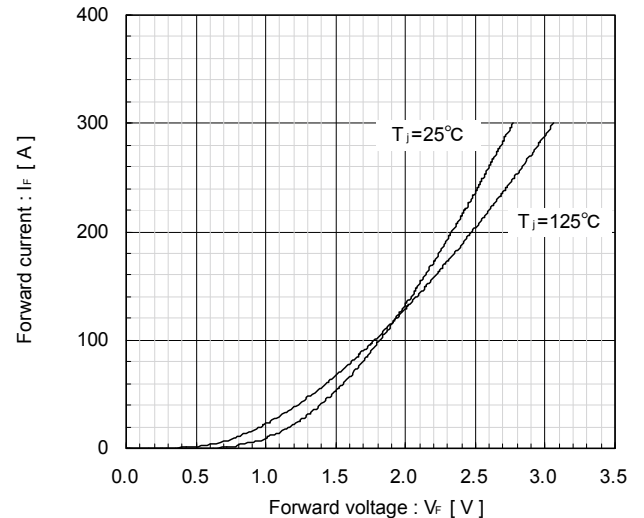
Collector current vs. Collector-Emitter voltage  
 $T_j = 125^\circ\text{C}$  [Terminal] (typ.)



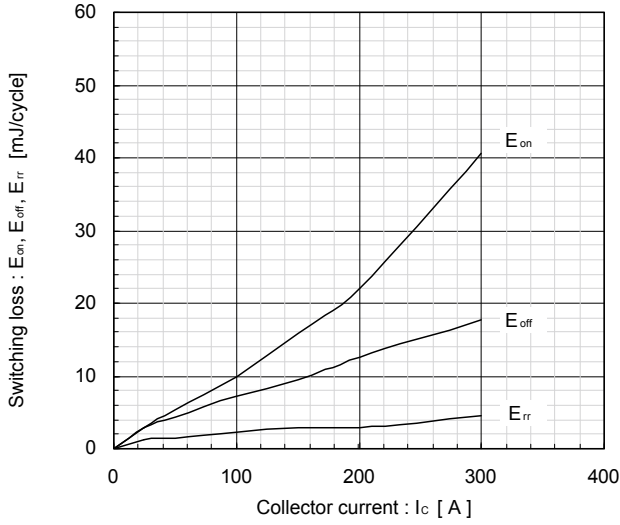
Forward current vs. Forward voltage  
 [Chip] (typ.)



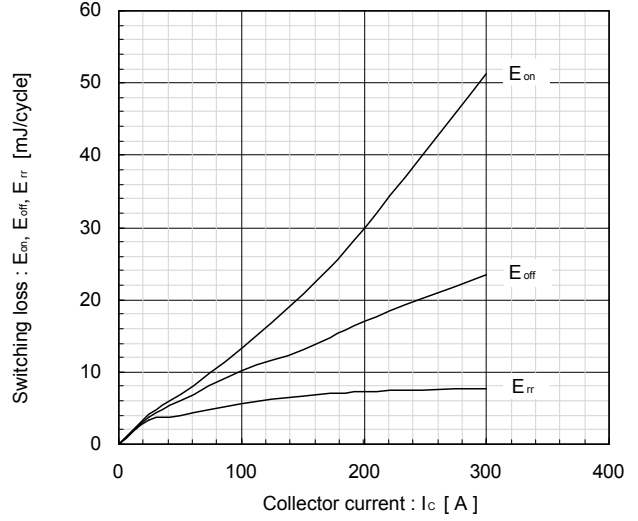
Forward current vs. Forward voltage  
 [Terminal] (typ.)



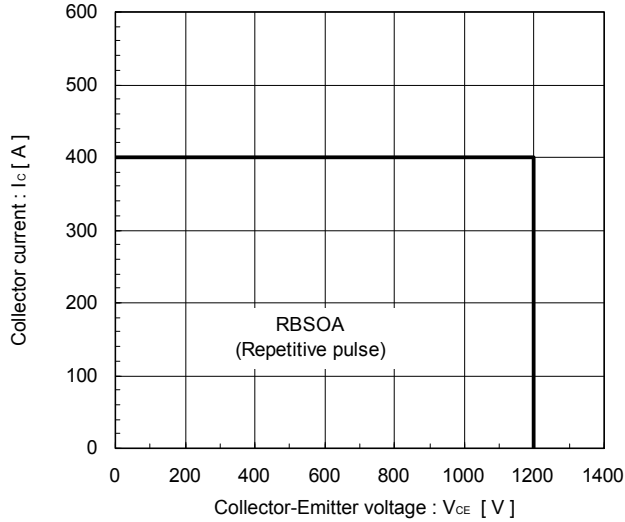
Switching Loss vs. Collector Current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_J=25^{\circ}C$



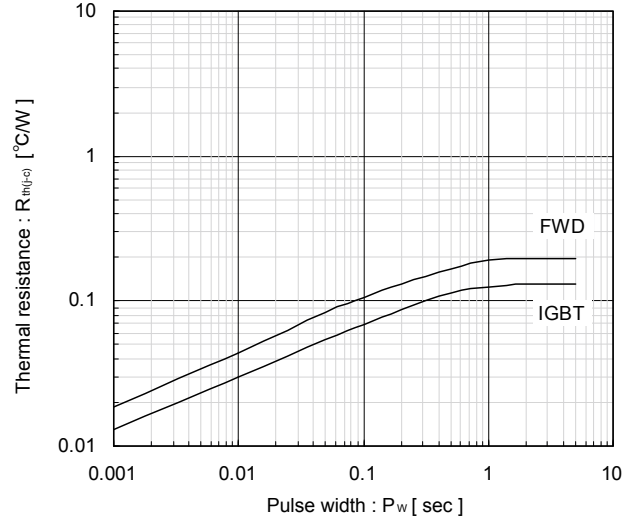
Switching Loss vs. Collector Current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_J=125^{\circ}C$



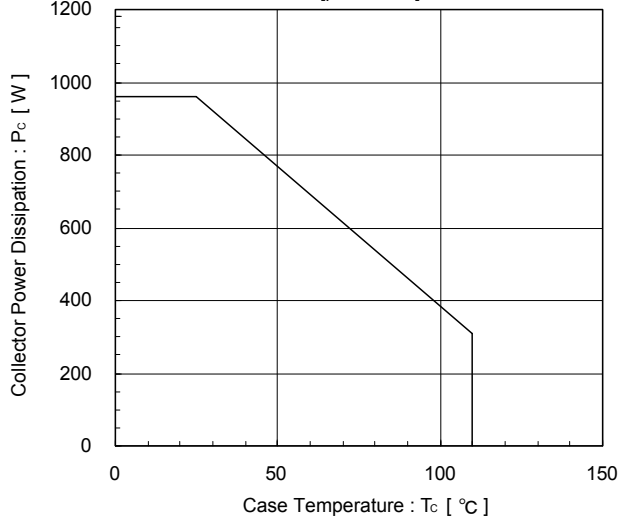
Reversed biased safe operating area  
 $V_{CC}=15V, T_J \leq 125^{\circ}C$  [Main Terminal] (min.)



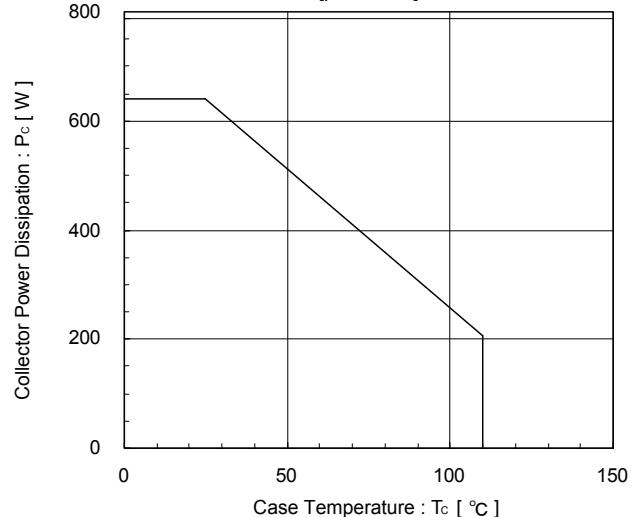
Transient thermal resistance (max.)



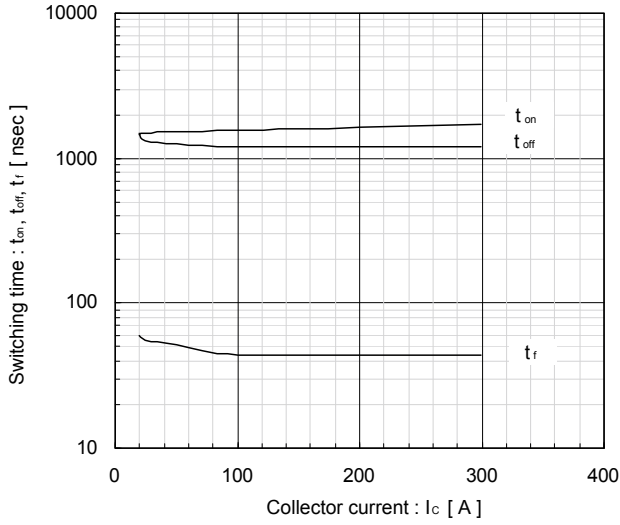
Power derating for IGBT (max.)  
 [per device]



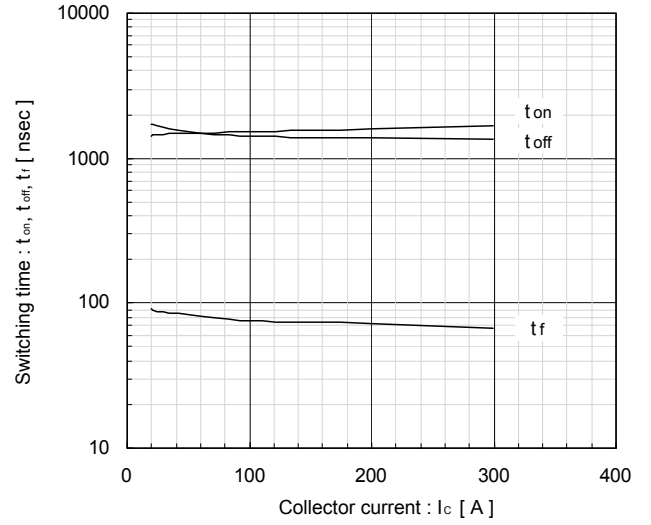
Power derating for FWD (max.)  
 [per device]



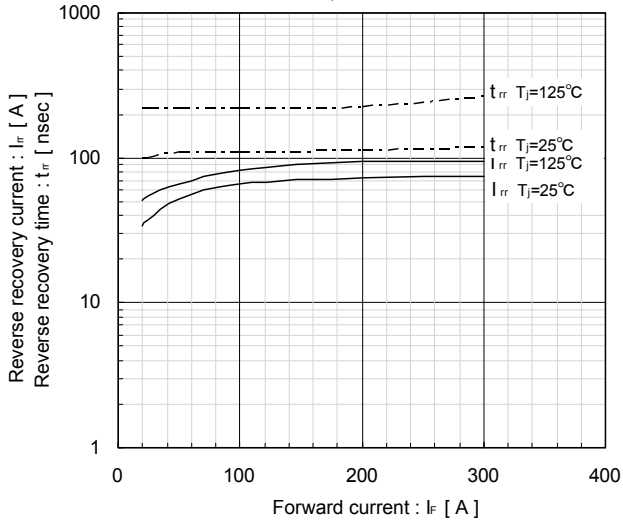
Switching time vs. Collector current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_j=25^\circ C$



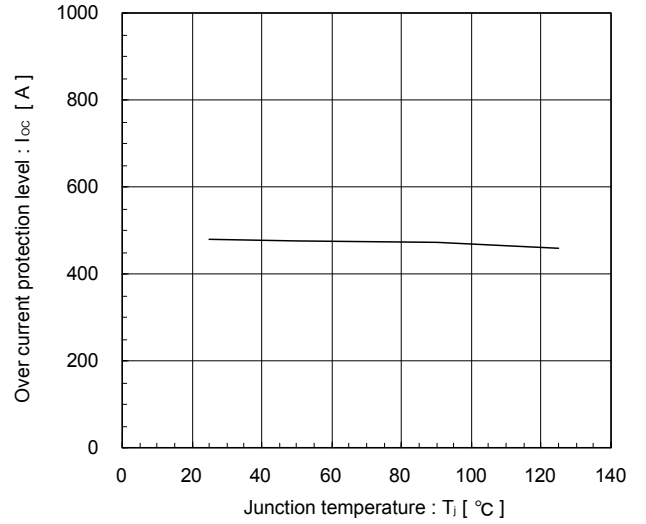
Switching time vs. Collector current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_j=125^\circ C$



Reverse recovery characteristics (typ.)  
 $t_{rr}, I_{rr}$  vs.  $I_f$

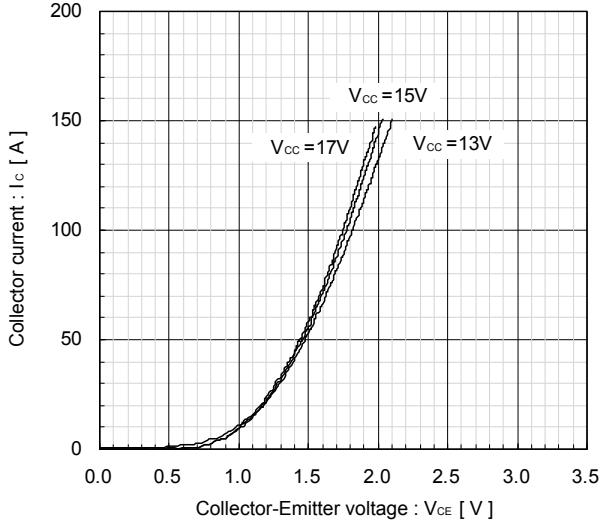


Over current protection vs. Junction temperature (typ.)  
 $V_{CC}=15V$

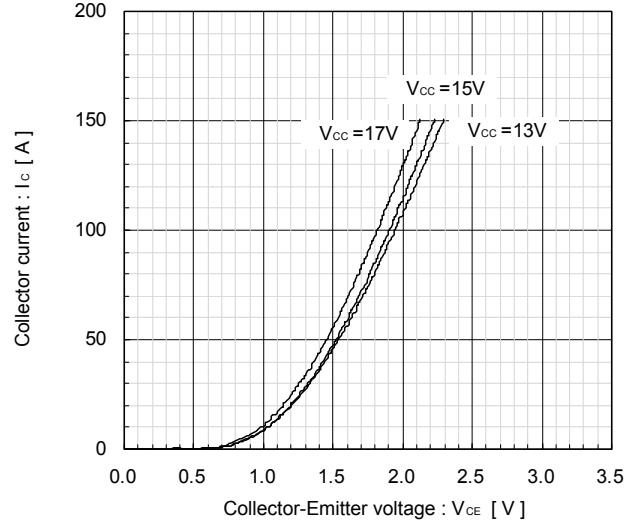


Brake

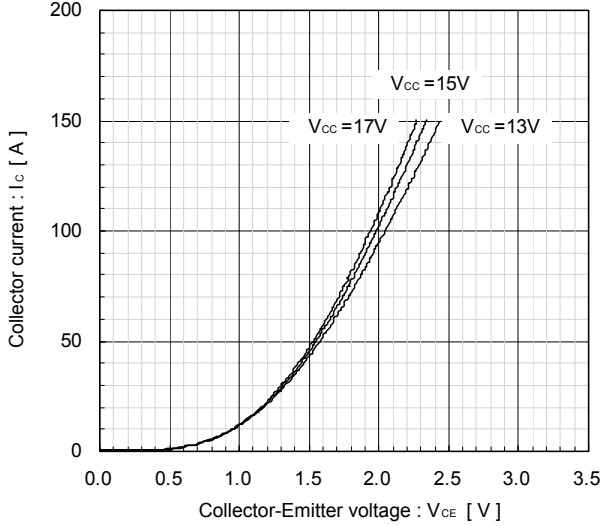
Collector current vs. Collector-Emitter voltage  
 $T_j = 25^\circ\text{C}$  [Chip] (typ.)



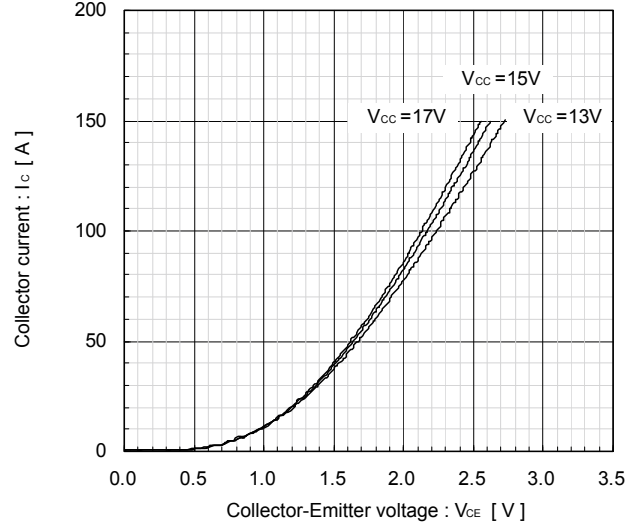
Collector current vs. Collector-Emitter voltage  
 $T_j = 25^\circ\text{C}$  [Terminal] (typ.)



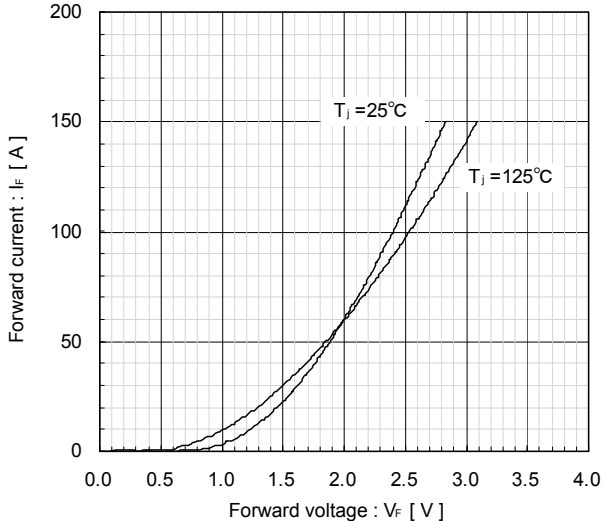
Collector current vs. Collector-Emitter voltage  
 $T_j = 125^\circ\text{C}$  [Chip] (typ.)



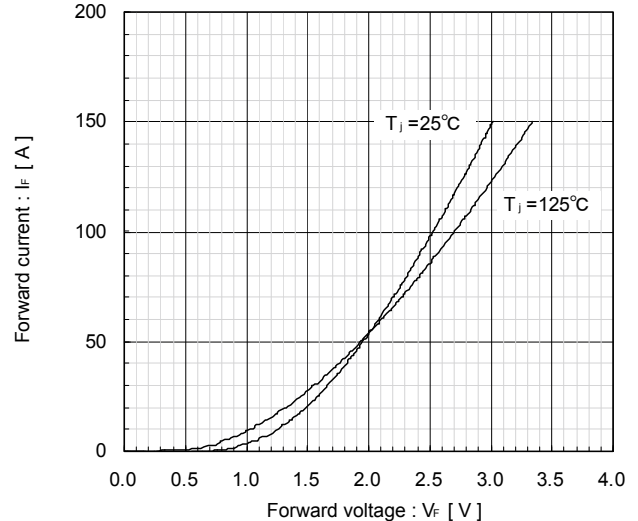
Collector current vs. Collector-Emitter voltage  
 $T_j = 125^\circ\text{C}$  [Terminal] (typ.)



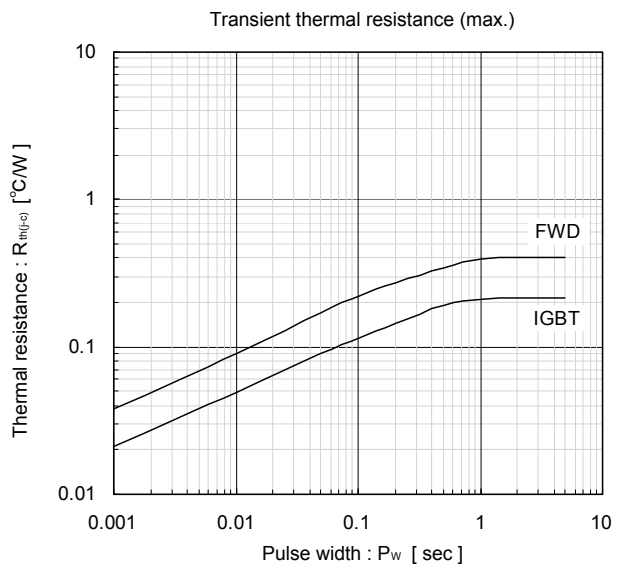
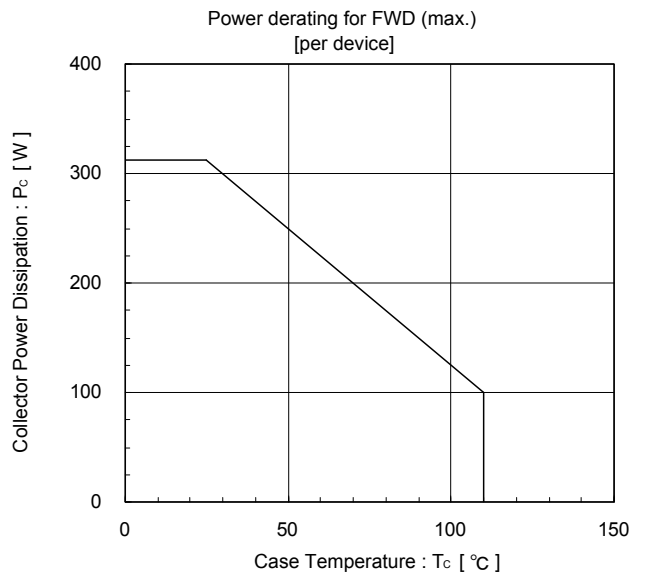
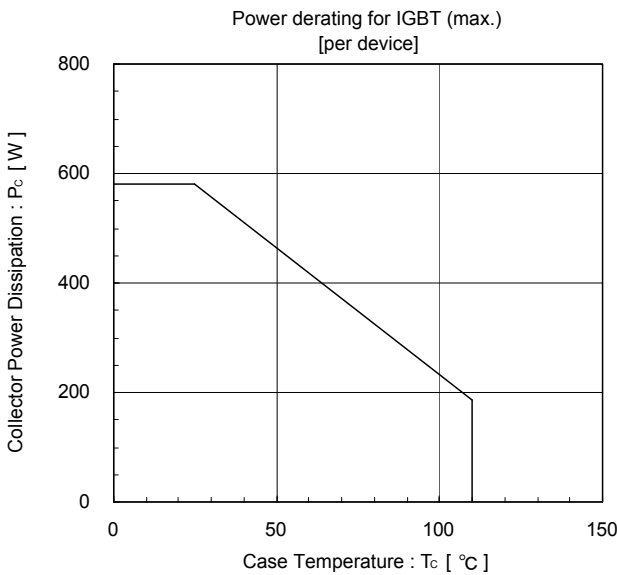
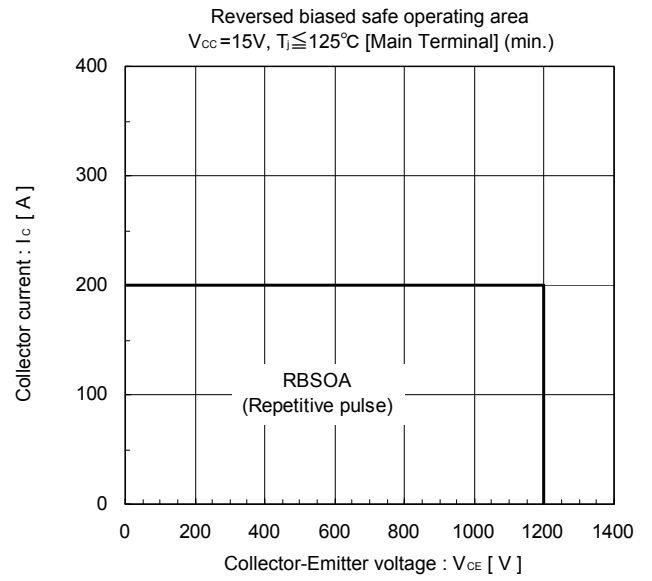
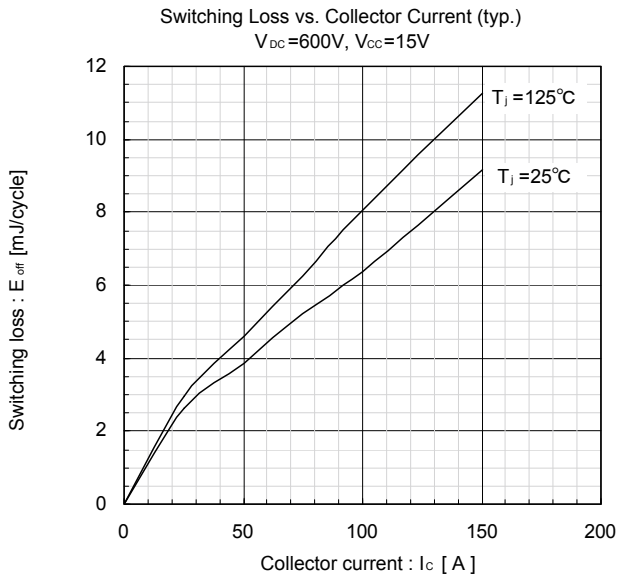
Forward current vs. Forward voltage  
 [Chip] (typ.)



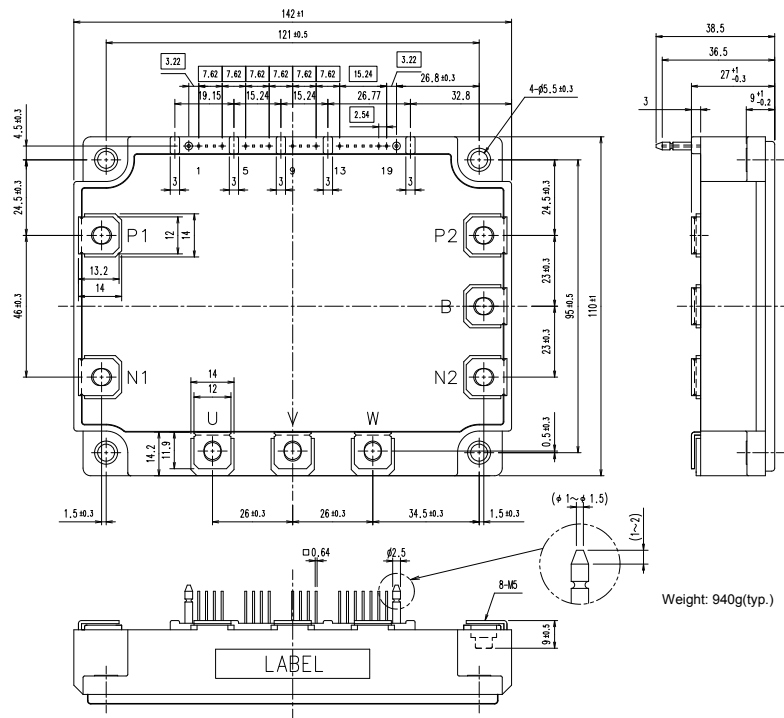
Forward current vs. Forward voltage  
 [Terminal] (typ.)







■ Outline Drawings, mm



**WARNING**

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  - Measurement equipment
  - Machine tools
  - Audiovisual equipment
  - Electrical home appliances
  - Personal equipment
  - Industrial robots etc.
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  - Traffic-signal control equipment
  - Gas leakage detectors with an auto-shut-off feature
  - Emergency equipment for responding to disasters and anti-burglary devices
  - Safety devices
  - Medical equipment
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